Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.33$ V at $I_F = 10$ A



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PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 30 A				
V _{RRM}	45 V				
I _{FSM}	320 A				
V _F at I _F = 30 A	0.47 V				
T _J max.	150 °C				
Package	TO-263AB				
Diode variations	Common cathode				

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
 RoHS compliant
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	VBT6045C	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	45	V		
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	60	٨		
	per diode		30	A		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	320	A		
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C		

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ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
	I _F = 10 A	T _A = 25 °C		0.44	-	- V	
	I _F = 15 A			0.47	-		
Instantaneous forward voltage per diade	I _F = 30 A			0.54	0.64		
Instantaneous forward voltage per diode	I _F = 10 A	T _A = 125 °C		0.33	-		
	I _F = 15 A			0.37	-		
	I _F = 30 A			0.47	0.56		
Poverse ourrent per diada	V 45 V	T _A = 25 °C	I _R ⁽²⁾	-	3000	μA	
Reverse current per diode	V _R = 45 V	T _A = 125 °C		18	50	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VBT64045C	UNIT	
Typical thermal resistance	per diode	$-R_{\theta JC}$	1.5	°C/W	
Typical thermal resistance	per device		0.8	C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-263AB	VBT6045C-E3/4W	1.38	4W	50/tube	Tube		
TO-263AB	VBT6045C-E3/8W	1.38	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

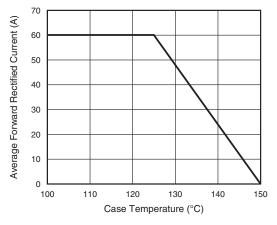


Fig. 1 - Maximum Forward Current Derating Curve

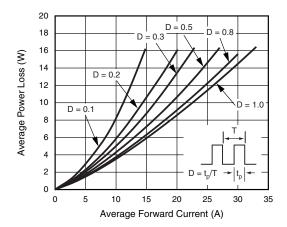


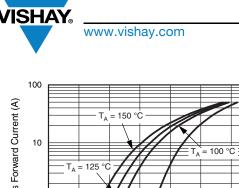
Fig. 2 - Forward Power Loss Characteristics Per Diode

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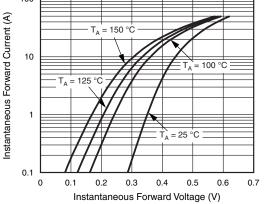


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

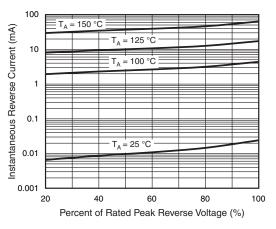
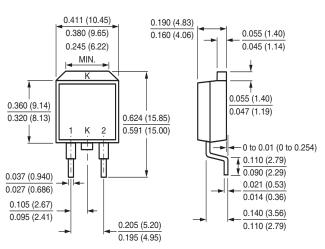


Fig. 4 - Typical Reverse Characteristics Per Diode





TO-263AB

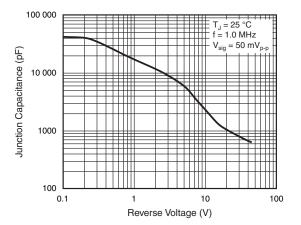


Fig. 5 - Typical Junction Capacitance Per Diode

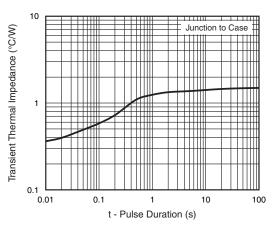
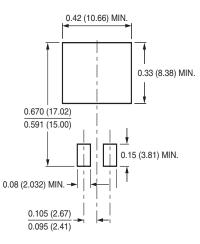


Fig. 6 - Typical Transient Thermal Impedance Per Diode

Mounting Pad Layout



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